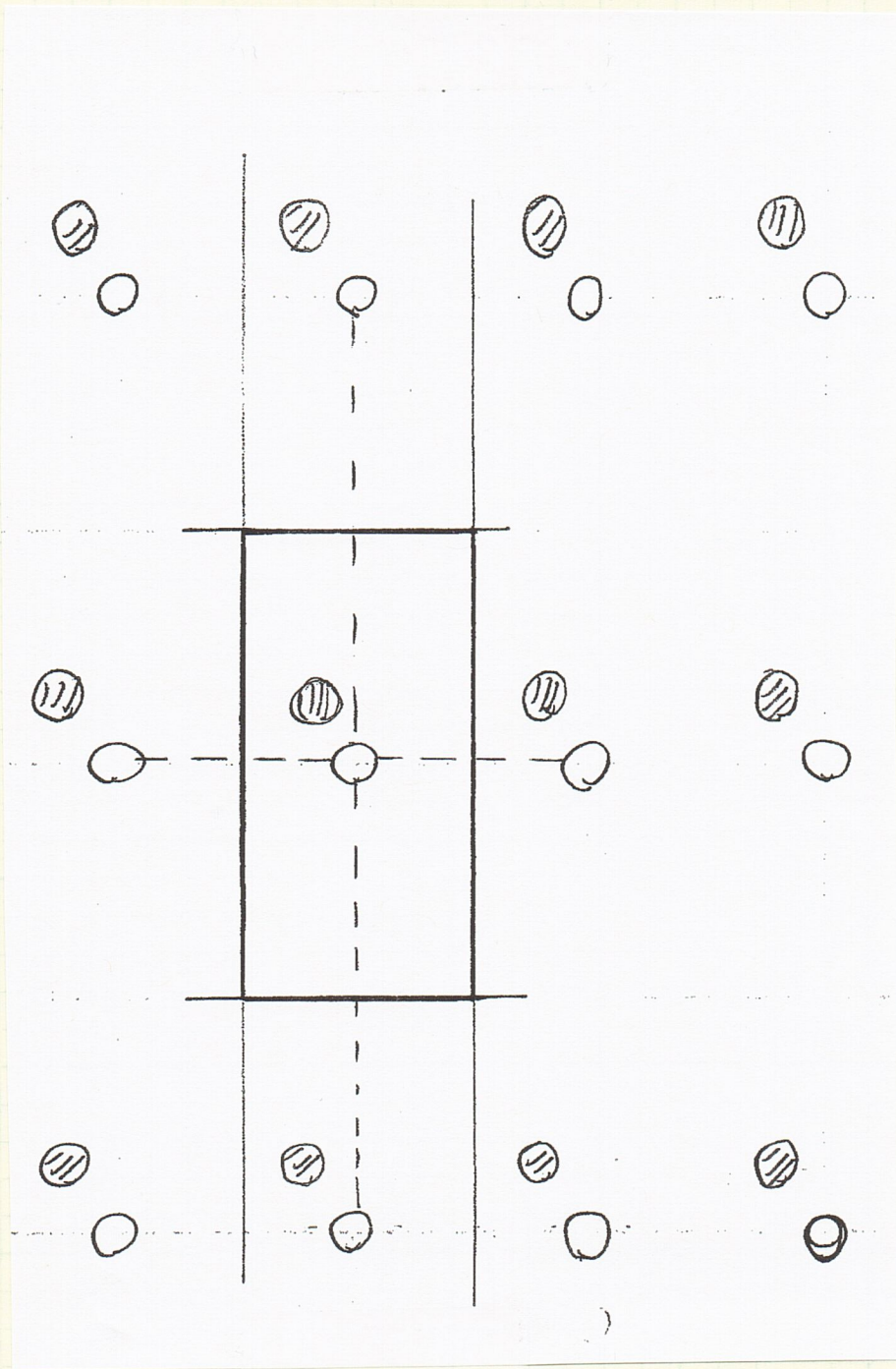


Q1

[Marks]

AMPAD

[ ]



[ ]

The basis is 2.

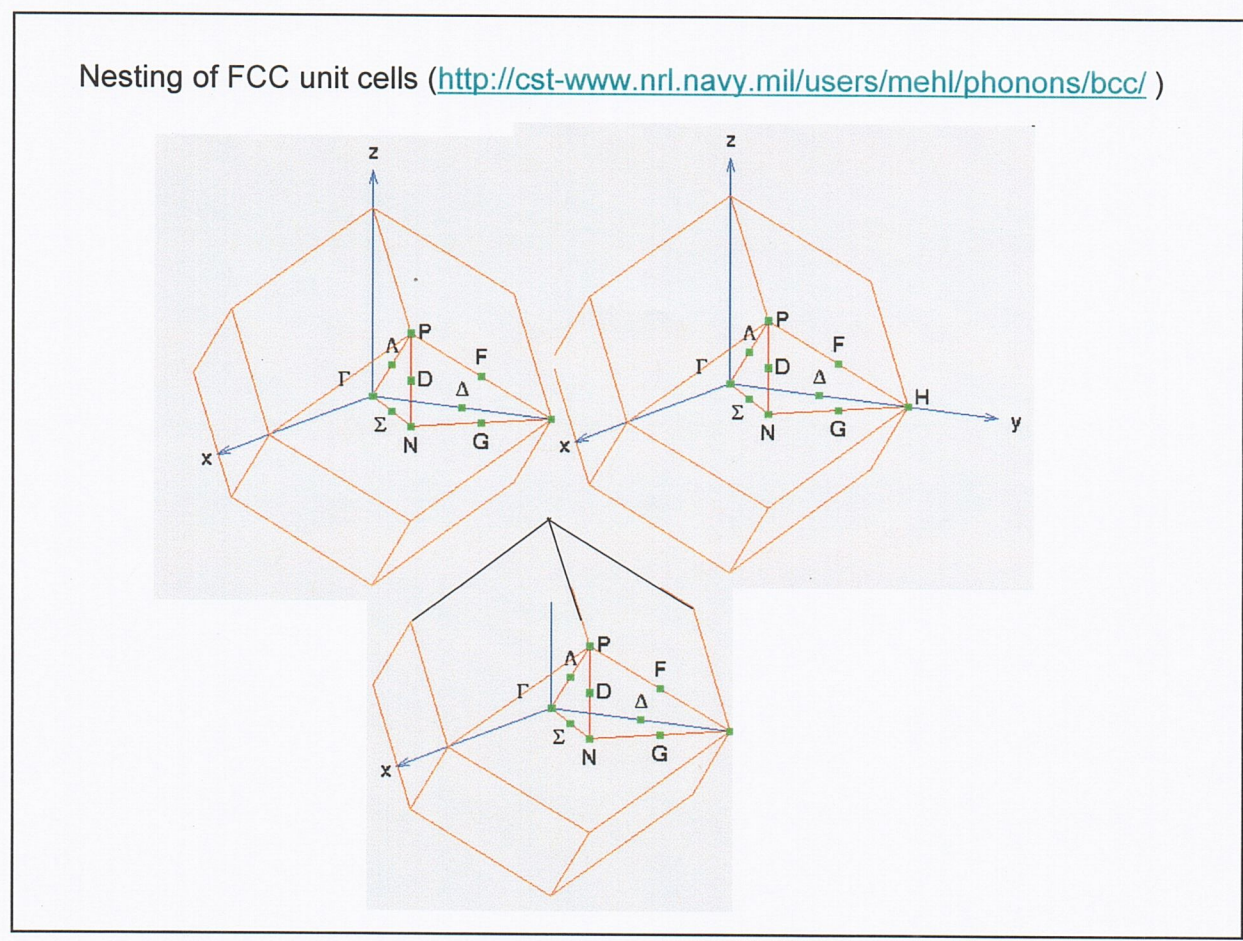


2

[1 for one cell]

[1/2 for reference]

[1/2 for showing nesting]



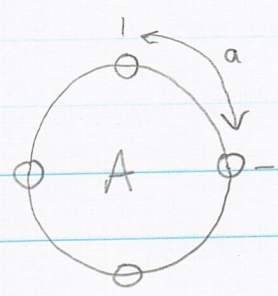
Each cell is a rhombic dodecahedron

[1] for

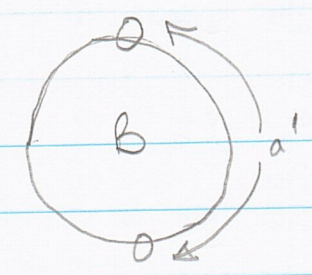


Q3

Consider cyclic representation:



$N = 4$   
 $Na = 4a$



$N' = 2$   
 $N'a' = 2a' = 2 \times 2a = 4a$

Allowed values of  $k$ :  $k_A = \frac{2\pi n}{Na}$   
 for  $-\frac{\pi}{a} \leq k_A \leq \frac{\pi}{a}$

$k_B = \frac{2\pi n}{N'a'}$   
 $-\frac{\pi}{a'} \leq k_B \leq \frac{\pi}{a'}$

range of  $n$  is:  $-\frac{N}{2} \leq n \leq \frac{N}{2}$

$-\frac{N'}{2} < n < \frac{N'}{2}$

# distinct  $k$ -values / band:  $N$   
 Allow for spin (2 states/ $k$ -value):  $2N$

$N'$  states / band  
 $2N'$  states / band

# electrons = # primitive cells  $\times$   $\frac{\text{atoms}}{\text{prim cell}}$   $\times$   $\frac{\text{val. electrons}}{\text{atom}}$

[1 for reasoning]

$= N \times 1 \times 1 = N$

$= N' \times 2 \times 1 = 2N'$

# filled bands =  $\frac{\text{electrons}}{\text{states / band}}$

$= \frac{N}{2N}$

$\frac{2N'}{2N'}$

half-full

full

[1 for B]

metal

semiconductor (or insulator)

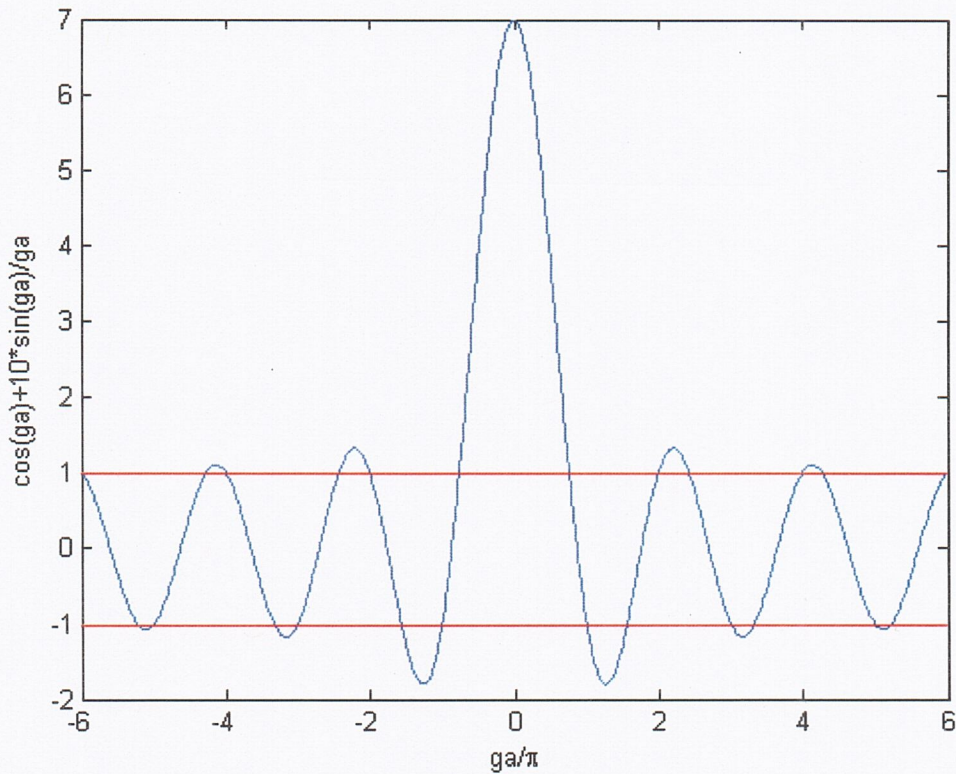


% Plotting Fig. 2.4  
 % EECE 480, September 2011

clear;

hbar=1.054573e-34; %[J-s]  
 m0=9.109390e-31; %[kg]  
 mstar=1;  
 A=6;  
 ga=linspace(-6\*pi,6\*pi,1000);  
 rhs=cos(ga)+A.\*sin(ga)./ga;

plot(ga./pi,rhs,ga./pi,ones(length(ga)), 'r', ga./pi,-ones(length(ga)), 'r');  
 xlabel('ga/pi'); ylabel('cos(ga)+10\*sin(ga)/ga');



[1 for  
code]

[2 for  
figure  
correctly  
labelled]



Q3

See next page

Name: \_\_\_\_\_

$$F_{11} = \frac{1}{2} \times \frac{1}{2} = \frac{1}{4}$$

$$F_{22} = \frac{1}{2} \times \frac{1}{2} = \frac{1}{4}$$

For A, number of \_\_\_\_\_ = \_\_\_\_\_



Q5

The material has  $N \times 4 \times 2 = 8N$  electrons

∴ first 4 bands are filled at 0 K, and the bandgap is between band #4 and band #5

From the plot from Q4, the top of band 4 occurs at  $g = 4\pi/a$ .

To find the bottom of band #5, solve (2.17) iteratively to find a solution slightly greater than  $4\pi/a$ .

The solution is  $g = 4.2679 \pi/a$ .

$$\text{from (2.6)} \quad \Delta E = E_g = \frac{h^2}{8m_0 a^2} \left[ (4.2679)^2 - (4)^2 \right]$$

$$\text{for } a = 0.75 \text{ nm}, \quad \underline{E_g = 1.49 \text{ eV}}$$

[1 for # filled bands]

[1 for identifying  $E_g$ ]

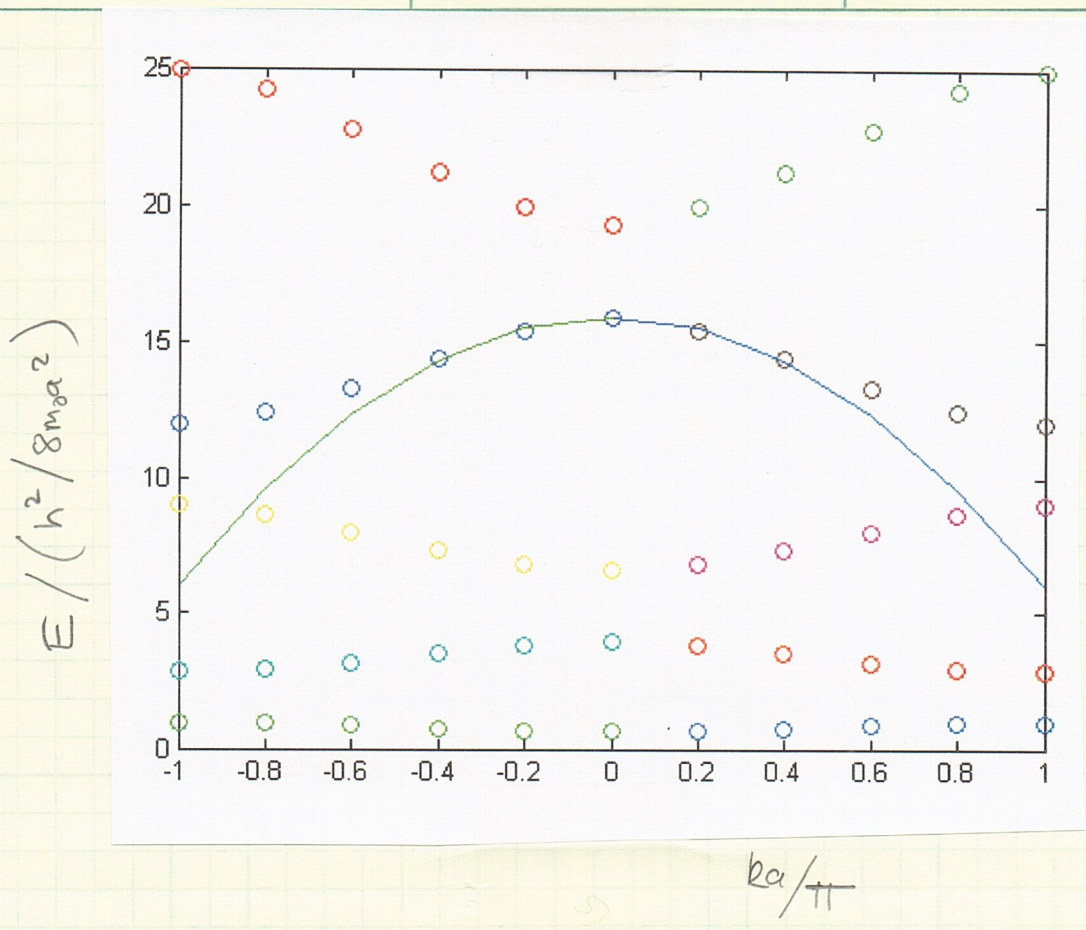
[1 for g values]

[1 for answer]



Q6

[1 1/2 for plot]

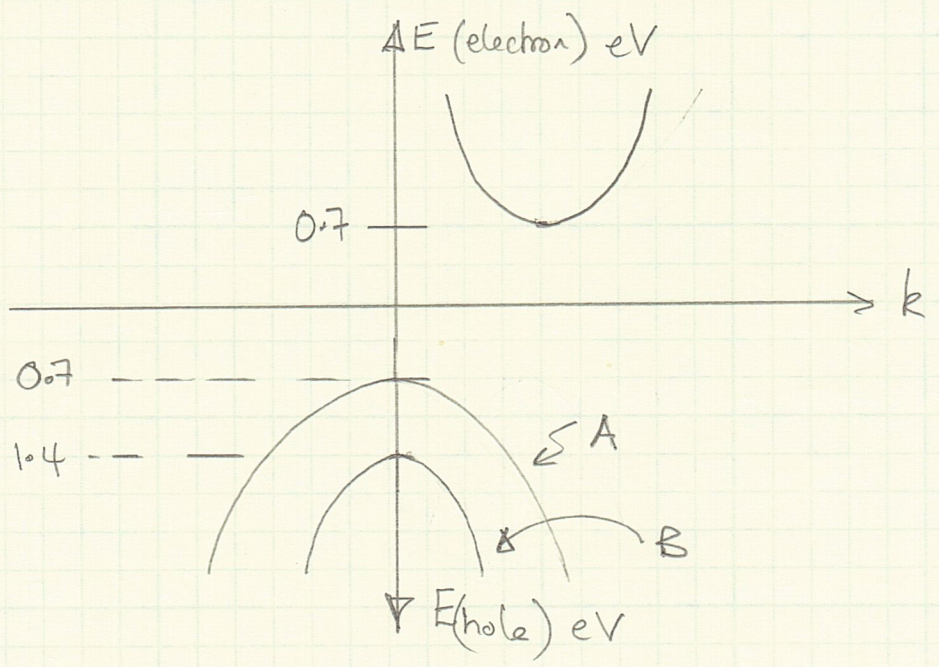


[1 1/2 for  $m_n^*$ ]

The fit shown here is for  $m_n^* = 0.1 m_0$

Q7

[1 for correct E-k plots]



$E_g(A) = 1.4 \text{ eV}, \quad E_g(B) = 2.1 \text{ eV}$

[1 for answers]

$m^* = \left[ \frac{1}{\hbar^2} \frac{d^2 E}{dk^2} \right]^{-1}$        $m_A^* \propto (2a)^{-1}, \quad m_B^* \propto (4a)^{-1} \quad \therefore m_A^* > m_B^*$



Q8.

[1 for reasoning]

CAMPAD

[1 for answer]

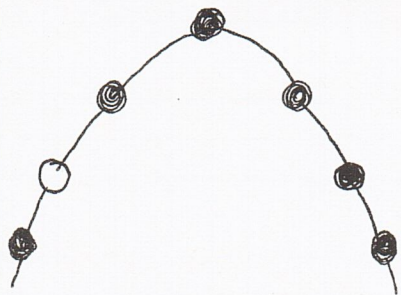


Fig. 2.10b

$$F_{x,ext} = \hbar \frac{\Delta k_x}{\Delta t} \quad (2.25)$$

$$= +q E_x \quad \text{for a hole}$$

$$\therefore \Delta k_x = q \frac{E_x}{\hbar} \Delta t$$

i.e., hole moves to more positive  $k_{xc}$

